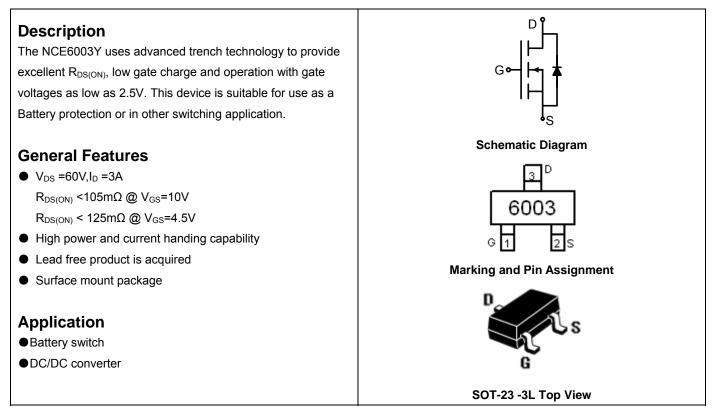




NCE N-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
6003	NCE6003Y	SOT-23-3L	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25[°]Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	3	А
Drain Current-Pulsed (Note 1)	I _{DM}	10	А
Maximum Power Dissipation	PD	1.7	W
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ extsf{ heta}JA}$	73.5	°C /W
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Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	60	65	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =60V, V_{GS} =0V	-	-	1	μA



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Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			1			
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	1.0	1.3	2.0	V
Drain Courses On State Desistance	P	V _{GS} =10V, I _D =3A	-	78	105	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =3A	-	95	125	mΩ
Forward Transconductance	g fs	V _{DS} =15V,I _D =2A		3	-	S
Dynamic Characteristics (Note4)	·			•		
Input Capacitance	C _{Iss}		-	247	-	PF
Output Capacitance	C _{oss}	V _{DS} =30V,V _{GS} =0V, F=1.0MHz	-	34	-	PF
Reverse Transfer Capacitance	Crss		-	19.5	-	PF
Switching Characteristics (Note 4)	·			•		
Turn-on Delay Time	t _{d(on)}		-	6	-	nS
Turn-on Rise Time	tr	V _{DD} =30V,I _D =1.5A	-	15	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{GEN} =1 Ω	-	15	-	nS
Turn-Off Fall Time	t _f		-	10	-	nS
Total Gate Charge	Qg)/ _20)// _20	-	6	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =30V,I _D =3A, V _{GS} =4.5V	-	1	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} -4.5V	-	1.3	-	nC
Drain-Source Diode Characteristics	·		·			
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =3A	-	-	1.2	V
Diode Forward Current (Note 2)	I _S		-	-	3	А

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

Surface Mounted on FR4 Board, t ≤ 10 sec.
Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.

4. Guaranteed by design, not subject to production



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Typical Electrical and Thermal Characteristics

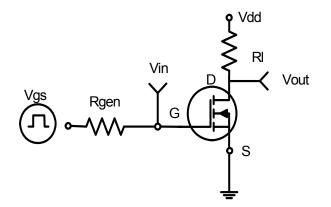
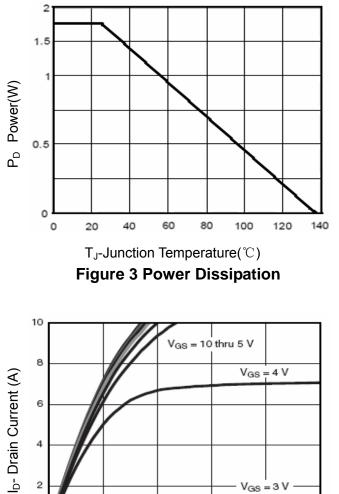
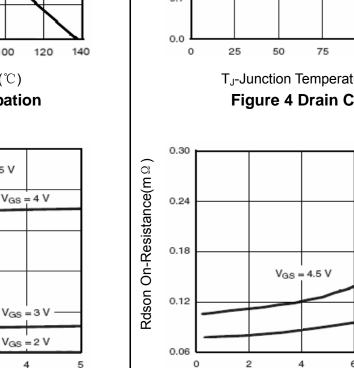


Figure 1:Switching Test Circuit





Vds Drain-Source Voltage (V) **Figure 5 Output Characteristics**

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2

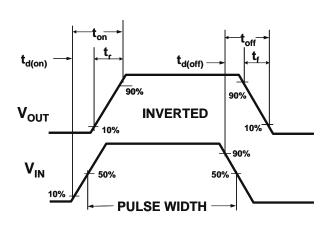
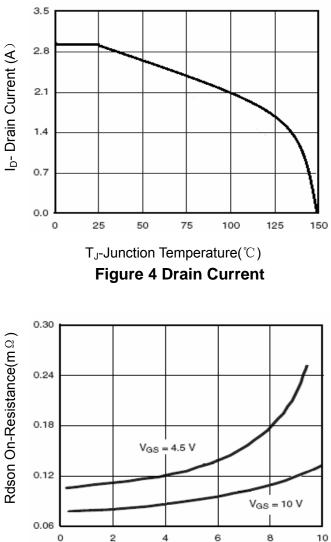


Figure 2:Switching Waveforms



I_D- Drain Current (A) Figure 6 Drain-Source On-Resistance

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2

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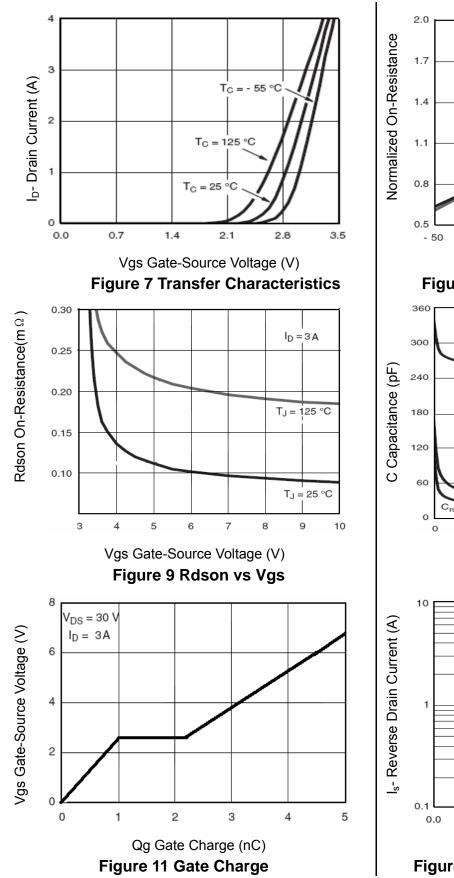
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Pb Free Product

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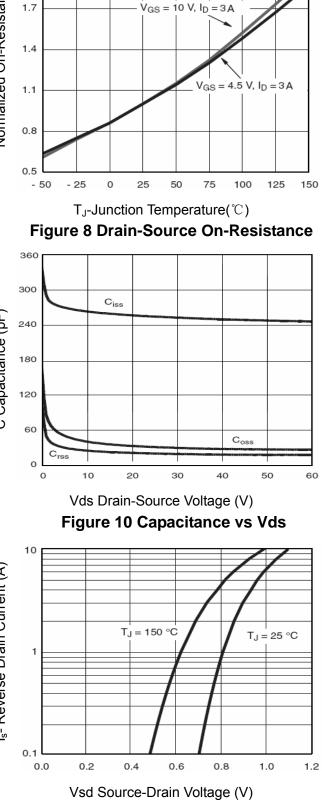


Figure 12 Source- Drain Diode Forward







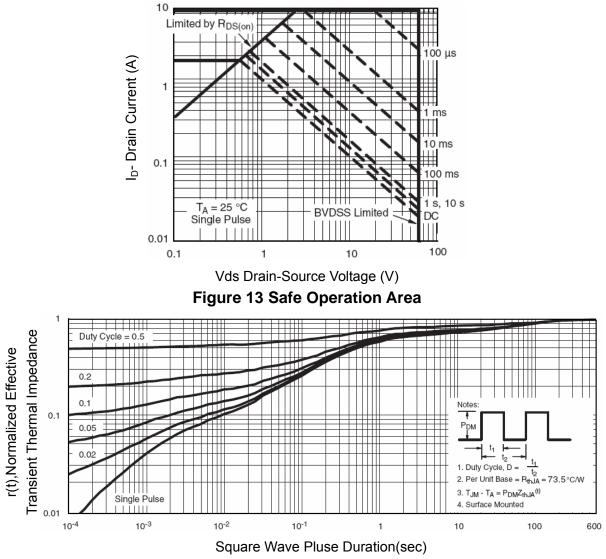


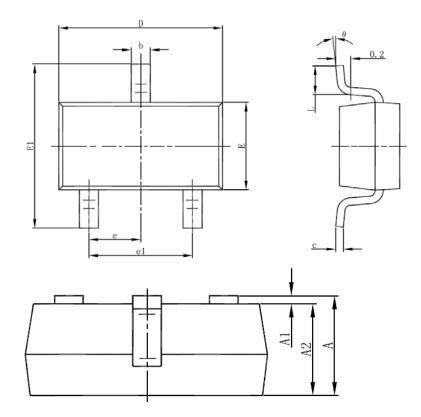
Figure 14 Normalized Maximum Transient Thermal Impedance







SOT-23-3L Package Information



Symbol	Dimensions Ir	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
с	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
е	0.950	(BSC)	0.037((BSC)	
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

Notes

1. All dimensions are in millimeters.

2. Tolerance ±0.10mm (4 mil) unless otherwise specified

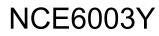
3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.

4. Dimension L is measured in gauge plane.

5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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